

SEMICONDUCTOR TECHNICAL DATA

Z5W27V

ZENER DIODE SILICON DIFFUSED-JUNCTION TYPE

BEST SUITED FOR OVERVOLTAGE PROTECTION OF ELECTRONIC SYSTEM:

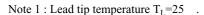
ELECTRONIC SYSTEM FOR USE IN AUTOMOBILES ELECTRONIC SYSTEM FOR COMMERCIAL USE ELECTRONIC SYSTEM FOR INDUSTRIAL USE FOR COMMUNICATIONS, CONTROLS, MEASURING INSTRUMENTS, ETC.

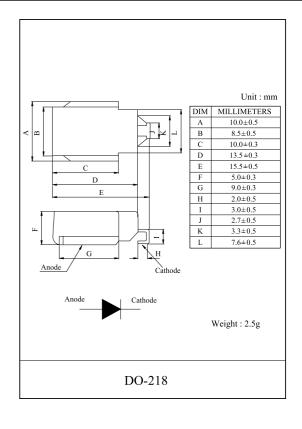
FEATURES

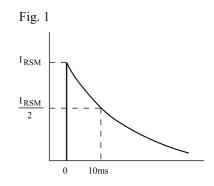
- Excellent clamp voltage characteristics that protect electronic system from any kind of surge.
- · High surge power withstanding capabilities that absorb load dump surge.
- · Excellent surge responsibility for steep surge absorption.
- Surface mount type is available for easy applications.
 Zxial lead type is also available.
- \cdot Although the typical zener voltage is V_Z =27V, we can provide the products other than the typical values.
- · Corresponds to taping packages. (500P/Reel)
- · Automotive AEC Q101 Qualified.
- · MSL Level 1 guaranteed (Tpeak = 260)
- · Qualified to AEC-Q101.

MAXIMUM RATING (Ta=25)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Allowable Power Dissipation	Р	5	W	
(Note 1)	1	3		
Peak Pulse Power Dissipation	P_{pp}	3,600	w	
With 10/1,000 µS wave form	1 рр	3,000	**	
Non-Repetitive Peak Reverse				
Surge Current	I_{RSM}	70	A	
(See Fig.1 for the exponents.)				
Operating Junction Temperature	T _j	-55 175		
Storage Temperature Range	T_{stg}	-40 150		

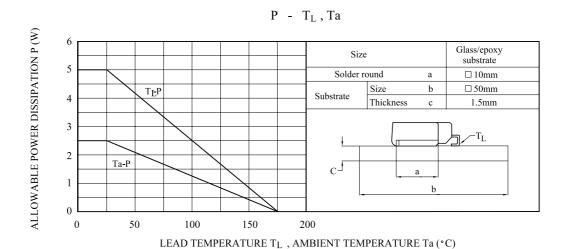


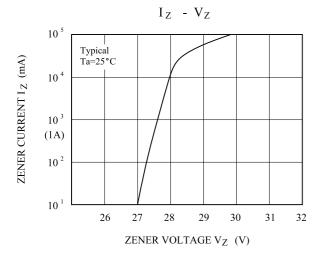


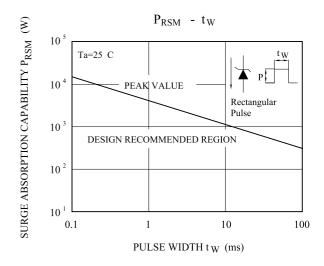


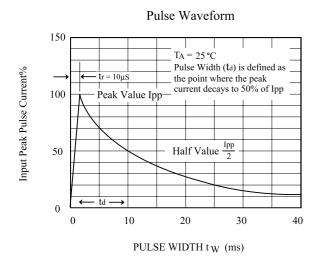
ELECTRICAL CHARACTERISTICS (Ta=25)

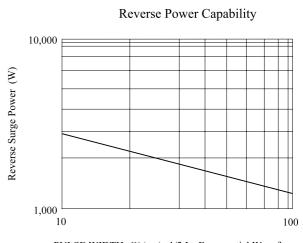
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Zener Voltage	V_Z	I _Z =10mA	24.0	27	30.0	V
Operating Resistance	r _d	I _Z =10mA	-	-	30	
Temperature Coefficient	Т	I _Z =10mA	-	23	36	mV/
Forward Voltage V _F	V_	I _F =6A	-	-	1.0	V
	V F	I _F =100A	-	-	1.2	V
Reverse Current	I_R	$V_R=22V$	-	-	10	μA
Clamping Voltage	$V_{\rm C}$	I _{RSM} =55A	-	-	40	V











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